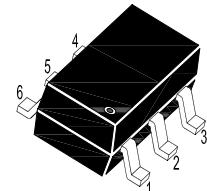
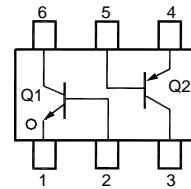


■ NPN / PNP Silicon Epitaxial Planar Transistors


1. Emitter 2. Base 3. Collector
4. Emitter 5. Base 6. Collector

■ Simplified outline(SOT-363)
■ Q1 Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	60	V
Collector Emitter Voltage	V_{CEO}	40	V
Emitter Base Voltage	V_{EBO}	6	V
Collector Current	I_C	200	mA

■ Q2 Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	40	V
Collector Emitter Voltage	$-V_{CEO}$	40	V
Emitter Base Voltage	$-V_{EBO}$	6	V
Collector Current	$-I_C$	200	mA

■ Q1Q2 Maximum Ratings ($T_a = 25^\circ\text{C}$)

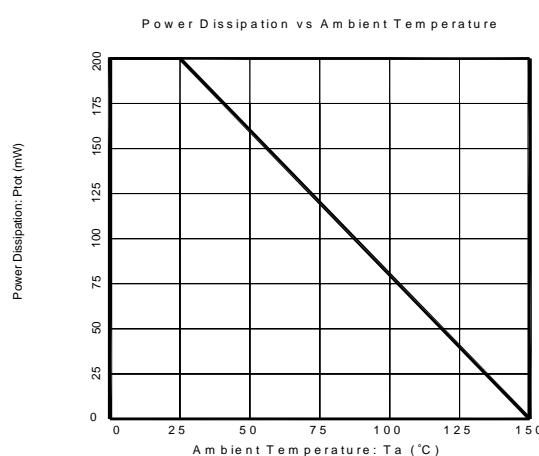
Parameter	Symbol	Value	Unit
Total Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	- 55 to + 150	°C

■ Q1 Electrical Characteristics at $T_a = 25^\circ\text{C}$

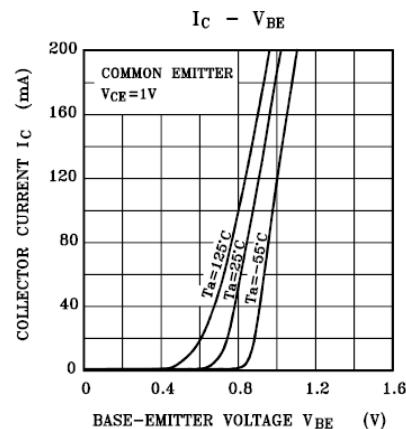
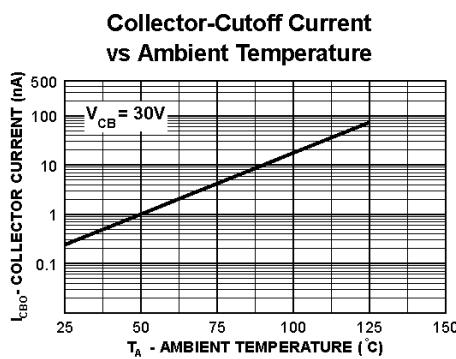
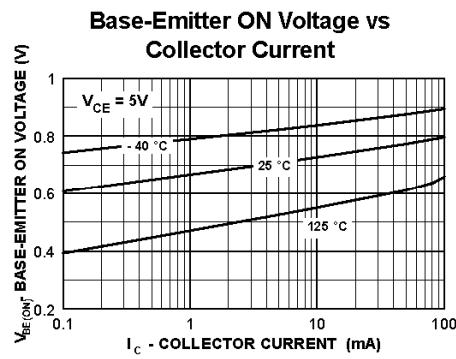
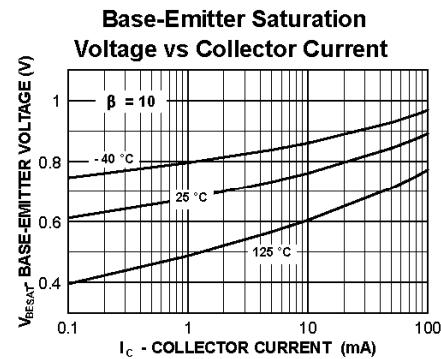
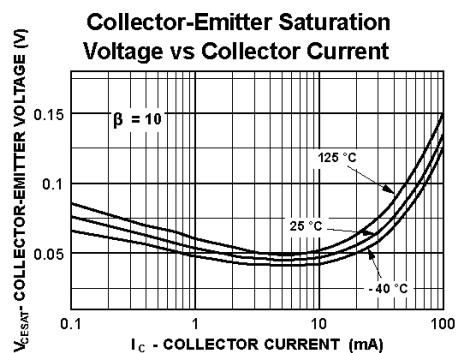
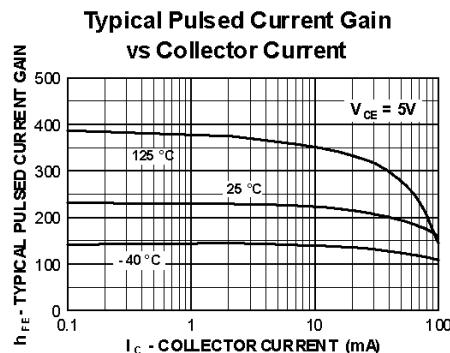
Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $V_{CE} = 1 \text{ V}$, $I_C = 0.1 \text{ mA}$ at $V_{CE} = 1 \text{ V}$, $I_C = 1 \text{ mA}$ at $V_{CE} = 1 \text{ V}$, $I_C = 10 \text{ mA}$ at $V_{CE} = 1 \text{ V}$, $I_C = 50 \text{ mA}$ at $V_{CE} = 1 \text{ V}$, $I_C = 100 \text{ mA}$	h_{FE}	40 70 100 60 30	- - 300 - -	- - - - -
Collector Base Cutoff Current at $V_{CB} = 30 \text{ V}$	I_{CBO}	-	50	nA
Emitter Base Cutoff Current at $V_{EB} = 6 \text{ V}$	I_{EBO}	-	50	nA
Collector Base Breakdown Voltage at $I_C = 10 \mu\text{A}$	$V_{(BR)CBO}$	60	-	V
Collector Emitter Breakdown Voltage at $I_C = 1 \text{ mA}$	$V_{(BR)CEO}$	40	-	V
Emitter Base Breakdown Voltage at $I_E = 10 \mu\text{A}$	$V_{(BR)EBO}$	6	-	V
Collector Emitter Saturation Voltage at $I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$ at $I_C = 50 \text{ mA}$, $I_B = 5 \text{ mA}$	$V_{CE(\text{sat})}$	- -	0.2 0.3	V V
Base Emitter Saturation Voltage at $I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$ at $I_C = 50 \text{ mA}$, $I_B = 5 \text{ mA}$	$V_{BE(\text{sat})}$	0.65 -	0.85 0.95	V V
Current Gain Bandwidth Product at $V_{CE} = 20 \text{ V}$, $I_C = 10 \text{ mA}$, $f = 100 \text{ MHz}$	f_T	300	-	MHz
Collector Output Capacitance at $V_{CB} = 5 \text{ V}$, $I_E = 0$, $f = 1 \text{ MHz}$	C_{ob}	-	4	pF
Delay Time at $V_{CC} = 3 \text{ V}$, $V_{BE} = 0.5 \text{ V}$, $I_C = 10 \text{ mA}$, $I_{B1} = 1 \text{ mA}$	t_d	-	35	ns
Rise Time at $V_{CC} = 3 \text{ V}$, $V_{BE} = 0.5 \text{ V}$, $I_C = 10 \text{ mA}$, $I_{B1} = 1 \text{ mA}$	t_r	-	35	ns
Storage Time at $V_{CC} = 3 \text{ V}$, $I_C = 10 \text{ mA}$, $I_{B1} = -I_{B2} = 1 \text{ mA}$	t_s	-	200	ns
Fall Time at $V_{CC} = 3 \text{ V}$, $I_C = 10 \text{ mA}$, $I_{B1} = -I_{B2} = 1 \text{ mA}$	t_f	-	50	ns

■ Q2 Electrical Characteristics at $T_a = 25^\circ\text{C}$

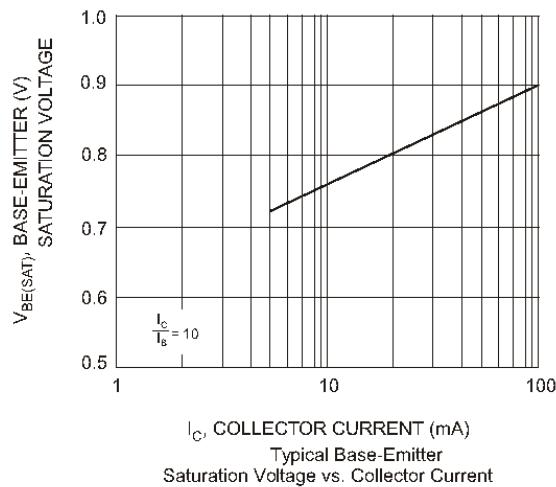
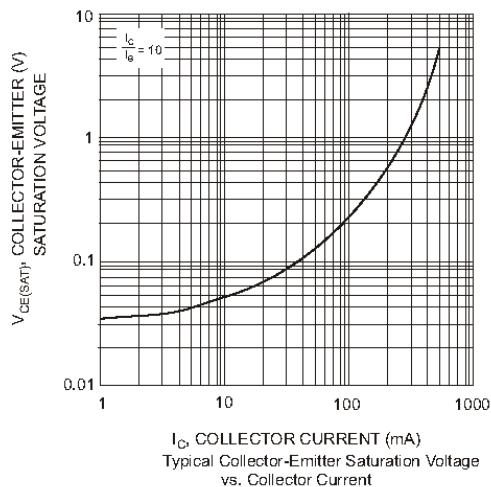
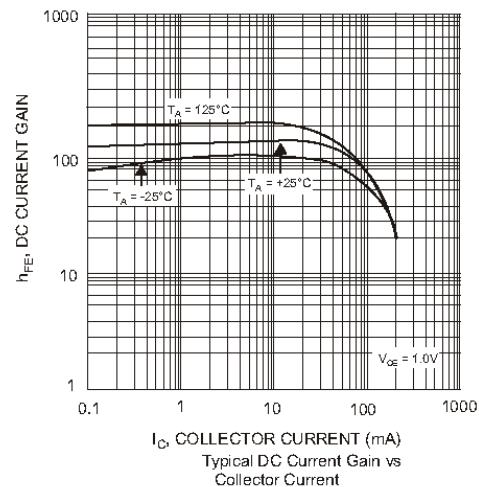
Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $-V_{CE} = 1 \text{ V}$, $-I_C = 0.1 \text{ mA}$	h_{FE}	60	-	-
at $-V_{CE} = 1 \text{ V}$, $-I_C = 1 \text{ mA}$	h_{FE}	80	-	-
at $-V_{CE} = 1 \text{ V}$, $-I_C = 10 \text{ mA}$	h_{FE}	100	300	-
at $-V_{CE} = 1 \text{ V}$, $-I_C = 50 \text{ mA}$	h_{FE}	60	-	-
at $-V_{CE} = 1 \text{ V}$, $-I_C = 100 \text{ mA}$	h_{FE}	30	-	-
Collector Base Cutoff Current at $-V_{CB} = 30 \text{ V}$	$-I_{CBO}$	-	50	nA
Emitter Base Cutoff Current at $-V_{EB} = 6 \text{ V}$	$-I_{EBO}$	-	50	nA
Collector Base Breakdown Voltage at $-I_C = 10 \mu\text{A}$	$-V_{(BR)CBO}$	40	-	V
Collector Emitter Breakdown Voltage at $-I_C = 1 \text{ mA}$	$-V_{(BR)CEO}$	40	-	V
Emitter Base Breakdown Voltage at $-I_E = 10 \mu\text{A}$	$-V_{(BR)EBO}$	6	-	V
Collector Emitter Saturation Voltage at $-I_C = 10 \text{ mA}$, $-I_B = 1 \text{ mA}$ at $-I_C = 50 \text{ mA}$, $-I_B = 5 \text{ mA}$	$-V_{CE(\text{sat})}$ $-V_{CE(\text{sat})}$	- -	0.25 0.4	V V
Base Emitter Saturation Voltage at $-I_C = 10 \text{ mA}$, $-I_B = 1 \text{ mA}$ at $-I_C = 50 \text{ mA}$, $-I_B = 5 \text{ mA}$	$-V_{BE(\text{sat})}$ $-V_{BE(\text{sat})}$	0.65 -	0.85 0.95	V V
Current Gain Bandwidth Product at $-V_{CE} = 20 \text{ V}$, $-I_C = 10 \text{ mA}$, $f = 100 \text{ MHz}$	f_T	250	-	MHz
Output Capacitance at $-V_{CB} = 5 \text{ V}$, $I_E = 0$, $f = 1 \text{ MHz}$	C_{obo}	-	4.5	pF
Delay Time at $-V_{CC} = 3 \text{ V}$, $-V_{BE} = 0.5 \text{ V}$, $-I_C = 10 \text{ mA}$, $-I_{B1} = 1 \text{ mA}$	t_d	-	35	ns
Rise Time at $-V_{CC} = 3 \text{ V}$, $-V_{BE} = 0.5 \text{ V}$, $-I_C = 10 \text{ mA}$, $-I_{B1} = 1 \text{ mA}$	t_r	-	35	ns
Storage Time at $-V_{CC} = 3 \text{ V}$, $-I_C = 10 \text{ mA}$, $-I_{B1} = I_{B2} = 1 \text{ mA}$	t_s	-	225	ns
Fall Time at $-V_{CC} = 3 \text{ V}$, $-I_C = 10 \text{ mA}$, $-I_{B1} = I_{B2} = 1 \text{ mA}$	t_f	-	75	ns



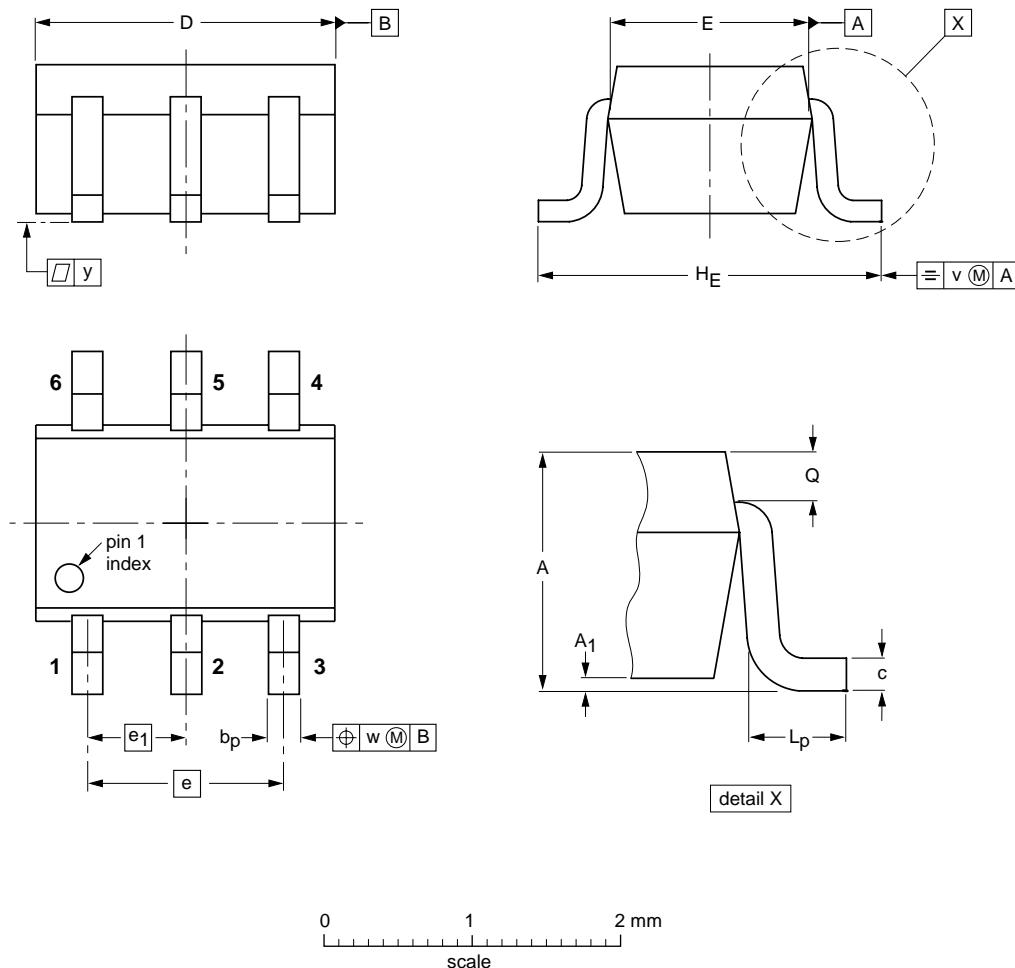
Q1(NPN transistor)



Q2(PNP transistor)



Package Outline SOT-363



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w	y
mm	1.1 0.8	0.1	0.30 0.20	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.25 0.15	0.2	0.2	0.1

Summary of Packing Options

Package	Package Description	Packing Quantity	Industry Standard
SOT-363	Tape/Reel, 7" reel	3000	EIA-481-1

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